



FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICATION	ATTY. DOCKET NO.: 9003-US-PA	APPLICATION NO.: 10/709,008
	APPLICANT: Chang	
	FILING DATE: April 7, 2004	GROUP 2812

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
S.B.G.	2002/0115245	2002/08/22	Chang et al.	438	166	2001/02/21
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FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
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EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)
S.B.G.	Brotherton et al., Excimer-Laser-Annealed Poly-Si Thin-Film Transistors in <i>IEEE Transactions On Electron Devices</i> , Vol. 40, No. 2, pp. 407-413, February 1993.
S.B.G.	Zeng et al., A Novel Two-Step Laser Crystallization Technique for Low-Temperature Poly-Si TFTs in <i>IEEE Transactions On Electron Devices</i> , Vol. 48, No. 5, pp. 1008-1010, May 2001.
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EXAMINER <i>S.B.G.</i>	DATE CONSIDERED <i>2-1-05</i>
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